RF and Microwave Power Power Technology Battle Born Amplifiers™

RFM1.6-30-500XR

1.6-30MHz 500W Class AB Linear High Performance Amplifier

* Class AB 500W XR-rated linear amplifier

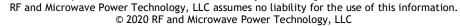
- 1.6-30MHz bandwidth
- 26dB typical gain
- 61% typical efficiency
- +/- 0.6dB typical gain flatness
- Temperature-compensated bias
- Optional bias disable (+5VDC)



The RFM1.6-30-500XR is an XR-rated high power amplifier for linear HF communication systems. It exhibits excellent full power linearity and gain flatness, and boasts an impressive 61% typical efficiency. It allows the high power system integrator to reduce internal amplifier count by up to half, substantially reducing system size and complexity, and increasing overall efficiency.

Specifications V_{sup} = +50VDC, I_{DQ} = 2.30A, P_{out} = 500W, T_{base} = 50°C, Z_{load} = 50 Ω					Maximum Ratings Operation beyond these ratings will void warranty.	
Parameter	Min	Тур	Max	Units	Parameter	Value
Freq. Range	1.6		30	MHz	V _{supply}	46-50VDC
P _{1dB}	500	See Figure 4		W	Bias Current	3.0A
Input Power		31	34	dBm	Drain Current	19A
Gain	23	26		dB	Load Mismatch*	5:1
Gain Flatness		+/-0.6	+/-1.0	dB	Maximum Housing Base Temperature See "Special Notes on Cooling", Page 4.	а
Drain Current		16.5	17.7	А		
Efficiency	56	61		%		
IRL		-19	-14	dB	Storage Temp.	-40°C to 85°C
f ₂		-53	-30	dBc	*All phase angles, 500W forward power, current limited to 19A for 5 seconds max.	
f ₃		-13	-10	dBc		
IMD ₃		-33	-28	dBc	Connectors: SMA	A input, N output
500W PEP, Δf=10kHz				Option Ordering Info		
Dimensions	3.70 X 6.20 X 2.20 (93.98 X 157.48 X 55.88)		inch (mm)	Bias Disable (+5V)	RFM1.6-30-500XR-DIS	

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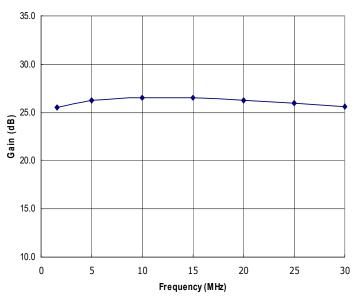


Figure 1: RFM1.6-30-500XR Typical Gain @ Pout = 500W.

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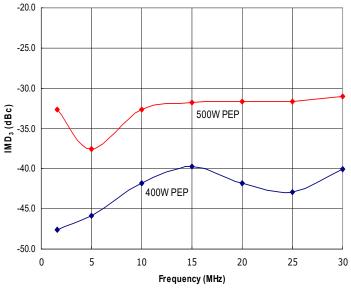
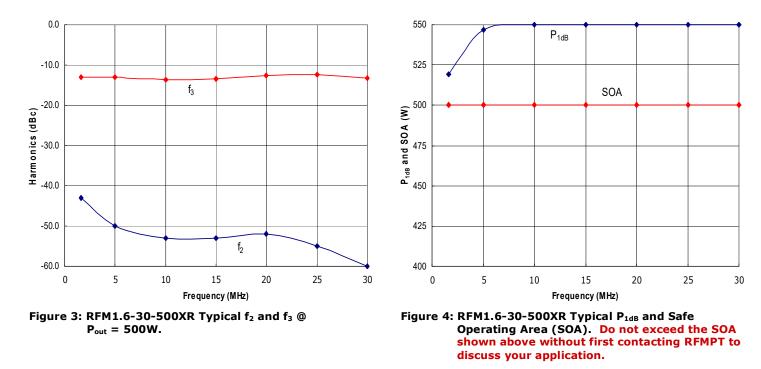


Figure 2: RFM1.6-30-500XR Typical IMD₃ @ Δf =10kHz, 500W PEP and 400W PEP.



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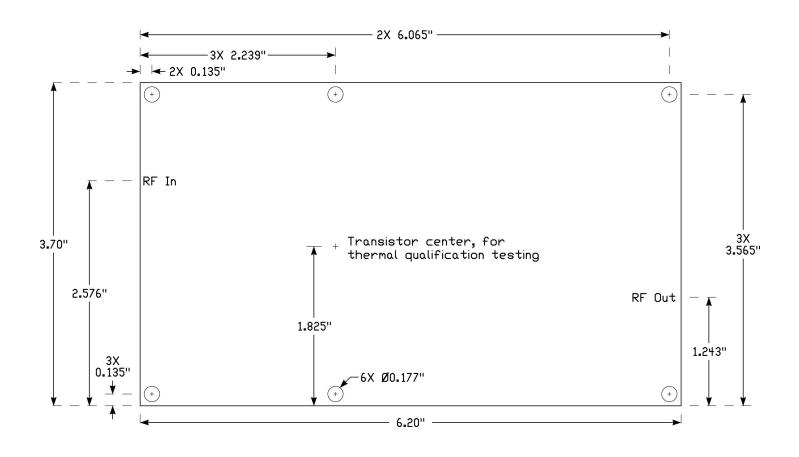


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Amplifier Mounting Hole and RF Connector Locations



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Special Notes on Cooling

This amplifier is capable of dissipating over 400W into even limited VSWR. This is substantial heat for a single transistor to safely dissipate. In normal operation into 50Ω , it will dissipate up to 365W at 20MHz, when running 500W CW. Dissipation will *increase* as the output power is reduced, until the output power is well below normal operating conditions. All operational scenarios therefore require careful attention to cooling, in order to keep the transistor die at a temperature low enough to ensure long term reliable operation.

This amplifier is supplied in a nickel-plated copper baseplate/vented ringframe construction for best thermal conductivity and output transformer cooling. The maximum rated housing base temperature is 65°C. This is to be measured, for cooling system qualification, on the bottom of the housing *directly below the center of the transistor* (see drawing on Page 3). A high performance heatsink will be required in order to maintain the housing base temperature at or below the specified limit. Required airflow can be preliminarily determined through thermal modeling, but must be confirmed by testing under intended worst case operating conditions.

In addition to providing proper airflow through the heatsink fins, air must also be directed through the vertical vent slots in the amplifier housing in order to cool the output transformers and DC feed structure. However, the cooling requirements of the transformers are less critical than that of the housing base and transistor. The goal is to avoid stagnant airspace inside the amplifier housing. Approximately 10-15cfm of normal ambient air *per RFM1.6-30-500XR* is sufficient for cooling the transformers.

High power 1.6-30MHz amplifiers frequently feed combiners, filters, a coupler, and ultimately an antenna. The resultant load presented to the RFM1.6-30-500XR will almost invariably be something other than 50Ω . Transistor dissipation has the potential to increase substantially beyond that seen with a perfectly matched load, depending on the phase angle of the reflected power. Customers are therefore *required* to use a high performance thermal compound, such as Wakefield Type 122, between the amplifier and heatsink. Use of standard performance thermal compounds, such as Wakefield Type 120, will void the warranty.

Finally, the transistor and amplifier are designed to withstand high VSWR. However, it is the user's responsibility to take appropriate measures to limit VSWR to the rated specification, as well as limit the current drawn by the amplifier. Unlimited exposure to high VSWR and/or high DC current can cause amplifier damage, and is not covered by the warranty. It is left to the end user to ensure that appropriate system protection measures are employed to avoid damage to the amplifier. Please contact RFMPT for guidance if you are unsure how to properly protect the amplifier or system electrically and/or thermally.

Important – Compatibility Warning

This amplifier is **not** interchangeable with our RFM2-30-500XR. The two amplifier models utilize different RF transistors and matching networks, and are **not** gain and phase matched to each other. System integrators must use one model or the other, exclusively, in any given system. Contact RFMPT for additional details.





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Bias Disable

The Bias Disable function does not completely eliminate RF output power if RF drive is present at the amplifier's input. Because this is a linear amplifier, feedback networks are utilized around the RF transistor, and will allow some limited amount of RF to be passed through the amplifier, even with the transistor bias disabled. In order to reduce RF output to zero, the RF drive source must be disabled. Our RFM1.5-30-25-HSD Class A amplifier is an excellent driver to pair with the RFM1.6-30-500XR. It offers a high speed disable function, and can be disabled in <1 μ sec.

General Instructions for Amplifier Use

- 1) When mounting on a heatsink, apply a layer of high performance thermal grease (Wakefield Type 122 or equivalent) to the underside of the amplifier housing. Thinner is better, but ensure that when mounted to your heatsink, contact across the **entire** housing base is made. Gaps and air bubbles will significantly reduce cooling, leading to possible amplifier damage. Use six #6-32 or M4 screws to mount the amplifier to your heatsink.
- 2) Guarantee sufficient airflow through the heatsink fins to keep the maximum baseplate temperature at or less than that specified in the Maximum Ratings section. Contact RFMPT for details on how to qualify your heatsink's performance, if needed.
- 3) Connect a proper signal source to the RF IN SMA connector, and desired load to the RF OUT N connector. Torque connectors to industry standards for the respective types.
- 4) Connect DC V_{supply} to the provided DC feedthrough filter. This amplifier can draw more than 19A into VSWR, so use of 12 gauge wire is highly recommended. Solder a wire of the same gauge to the GND lug. Ensure that the connections are of proper polarity, and within the voltage range in the Maximum Ratings section.
- 5) Apply DC power, then sufficient RF drive to achieve desired output level. Ensure that the Safe Operating Area (SOA) power level indicated in Figure 4 is not exceeded, or amplifier damage may occur, and will void the warranty.
- 6) To disconnect the amplifier, first remove the RF drive, then DC power, then the RF connections.

Contact our factory at <u>sales@rfmpt.com</u> with any questions, or for special options, extended frequency range operation, testing requirements, and/or other operating conditions not specified in this document.

Document Control

Revision	Date	Notes		
А	7-3-2020	Initial release.		

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